# **1PS76SB21**; **BAT721** series

## Schottky barrier diodes in small packages

Rev. 06 — 21 December 2006

**Product data sheet** 

### 1. Product profile

### 1.1 General description

Planar Schottky barrier diodes with an integrated guard ring for stress protection. Encapsulated in small Surface-Mounted Device (SMD) plastic packages.

Table 1. Product overview

Type number	Package		Configuration
	NXP	JEITA	
1PS76SB21	SOD323	SC-76	single
BAT721	SOT23	-	single
BAT721A	SOT23	-	dual common anode
BAT721C	SOT23	-	dual common cathode
BAT721S	SOT23	-	dual series

#### 1.2 Features

- Low forward voltage
- Small SMD plastic packages
- Low capacitance

### 1.3 Applications

- Ultra high-speed switching
- Voltage clamping
- Line termination
- Reverse polarity protection

#### 1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						
I <sub>F</sub>	forward current		-	-	200	mA
$V_R$	reverse voltage		-	-	40	V
$V_{F}$	forward voltage	$I_F = 200 \text{ mA}$	<u>[1]</u> -	-	550	mV

<sup>[1]</sup> Pulse test:  $t_p \le 300~\mu s;~\delta \le 0.02.$ 



### 2. Pinning information

Table 3. **Pinning** Pin Description Simplified outline **Symbol** 1PS76SB21 [1] 1 cathode 1 - 2 2 anode sym001 **BAT721** 1 anode 3 2 not connected 3 cathode n.c. 006aaa144 **BAT721A** cathode (diode 1) 3 2 cathode (diode 2) 3 anode (diode 1), anode (diode 2) 006aaa439 1 2 006aaa144 **BAT721C** 1 anode (diode 1) 3 2 anode (diode 2) 3 cathode (diode 1), cathode (diode 2) 006aaa438 2 006aaa144 **BAT721S** 1 anode (diode 1) 3 2 cathode (diode 2) 3 cathode (diode 1), anode (diode 2) 006aaa437 2 1 006aaa144

[1] The marking bar indicates the cathode.

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### 3. Ordering information

Table 4. Ordering information

Type number	Package				
	Name	Description	Version		
1PS76SB21	SC-76	plastic surface-mounted package; 2 leads	SOD323		
BAT721	-	plastic surface-mounted package; 3 leads	SOT23		
BAT721A					
BAT721C					
BAT721S					

### 4. Marking

Table 5. Marking codes

Type number	Marking code <sup>[1]</sup>
1PS76SB21	S1
BAT721	L7*
BAT721A	L8*
BAT721C	L9*
BAT721S	L0*

<sup>[1] \* = -:</sup> made in Hong Kong

### 5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per diode					
$V_R$	reverse voltage		-	40	V
I <sub>F</sub>	forward current		-	200	mA
I <sub>FSM</sub>	non-repetitive peak forward current	half sine wave; JEDEC method; $t_p = 8.3 \text{ ms}$	-	1	Α
Tj	junction temperature		-	125	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

<sup>\* =</sup> p: made in Hong Kong

<sup>\* =</sup> t: made in Malaysia

<sup>\* =</sup> W: made in China

### 6. Thermal characteristics

Table 7 Thermal characteristics

Table 1.	Thermal Characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient	in free air	<u>[1]</u>			
	1PS76SB21		-	-	450	K/W
	BAT721		-	-	500	K/W
	BAT721A		-	-	500	K/W
	BAT721C		-	-	500	K/W
	BAT721S		-	-	500	K/W

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

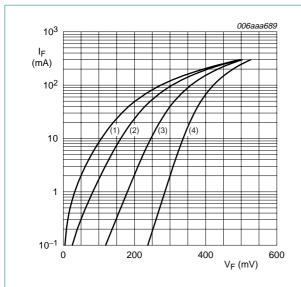
### 7. Characteristics

Table 8. Characteristics

 $T_{amb} = 25 \,^{\circ}C$  unless otherwise specified.

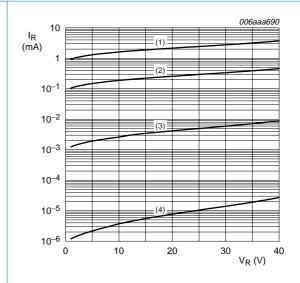
anno		•				
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode	)					
V <sub>F</sub> forward vo	forward voltage	I <sub>F</sub> = 10 mA	<u>[1]</u> _	-	300	mV
		I <sub>F</sub> = 100 mA	<u>[1]</u> _	-	420	mV
		I <sub>F</sub> = 200 mA	<u>[1]</u> _	-	550	mV
I <sub>R</sub>	reverse current	V <sub>R</sub> = 30 V	-	-	15	μΑ
		$V_R = 30 \text{ V}; T_j = 100 ^{\circ}\text{C}$	-	-	3	mA
C <sub>d</sub>	diode capacitance	$V_R = 0 V; f = 1 MHz$	-	40	50	pF

<sup>[1]</sup> Pulse test:  $t_p \le 300 \ \mu s; \ \delta \le 0.02.$ 



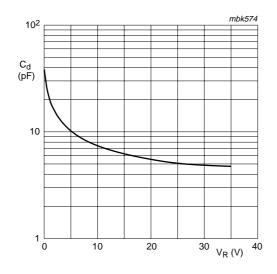
- (1)  $T_{amb} = 125 \, ^{\circ}C$
- (2)  $T_{amb} = 85 \,^{\circ}C$
- (3)  $T_{amb} = 25 \, ^{\circ}C$
- (4)  $T_{amb} = -40 \, ^{\circ}C$

Fig 1. Forward current as a function of forward voltage; typical values



- (1)  $T_{amb} = 125 \, ^{\circ}C$
- (2)  $T_{amb} = 85 \, ^{\circ}C$
- (3)  $T_{amb} = 25 \, ^{\circ}C$
- (4)  $T_{amb} = -40 \, ^{\circ}C$

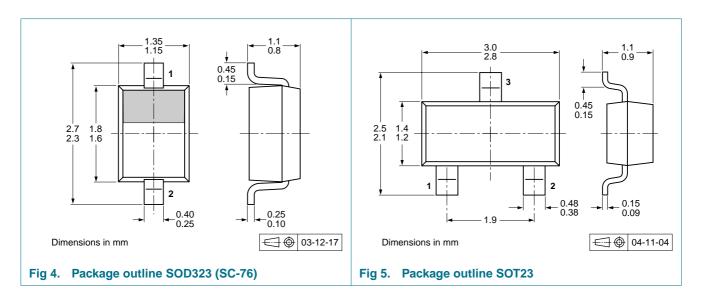
Fig 2. Reverse current as a function of reverse voltage; typical values



 $T_{amb} = 25 \,^{\circ}\text{C}$ ;  $f = 1 \, \text{MHz}$ 

Fig 3. Diode capacitance as a function of reverse voltage; typical values

## 8. Package outline



### 9. Packing information

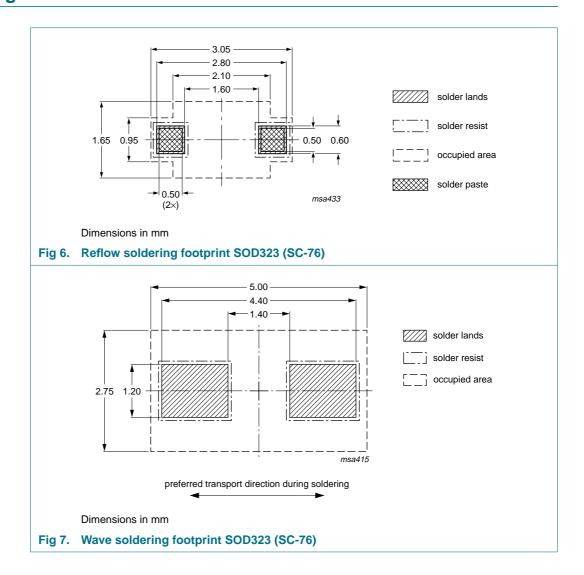
Table 9. Packing methods

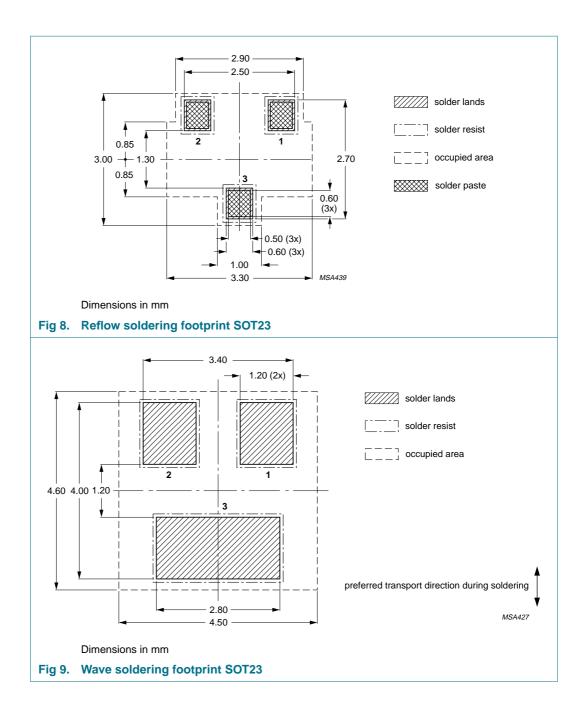
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing	Packing quantity		
			3000	10000		
1PS76SB21	SOD323	4 mm pitch, 8 mm tape and reel	-115	-135		
BAT721	SOT23	4 mm pitch, 8 mm tape and reel	-215	-235		
BAT721A						
BAT721C						
BAT721S						

[1] For further information and the availability of packing methods, see Section 13.

### 10. Soldering





## 11. Revision history

#### Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
1PS76SB21_BAT721_SER_6	20061221	Product data sheet	-	1PS76SB21_BAT721 _SER_5			
Modifications:	<ul> <li>Amended Ta</li> </ul>	able 10 "Revision history"					
1PS76SB21_BAT721_SER_5	20061205	Product data sheet	-	BAT721_SERIES_4 1PS76SB21_3			
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the new identification.</li> </ul>						
	<ul> <li>Legal texts h</li> </ul>	nave been adapted to the ne	ew company name wh	ere appropriate.			
	<ul> <li>This data sh</li> <li>1PS76SB21</li> </ul>	eet is a combination of data _3.	a sheets BAT721_SER	IES_4 and			
	• Table 1 "Pro	duct overview": added					
	<ul><li>Section 1.2 '</li></ul>	"Features": amended					
<ul> <li><u>Section 1.3 "Applications"</u>: amended</li> </ul>							
	Table 2 "Quick reference data": added						
	<ul> <li><u>Table 5 "Marking codes"</u>: for 1PS76SB21 amended</li> </ul>						
	<ul><li>Table 5 "Mar</li></ul>	king codes": enhanced table	le note section				
	<ul> <li>Table 6 "Lim</li> </ul>	iting values": indication per	diode added				
	• Table 6 "Lim	iting values": for 1PS76SB2	21 I <sub>FSM</sub> condition amer	nded			
	<ul> <li>Table 6 "Lim</li> </ul>	iting values": T <sub>amb</sub> ambient	temperature added				
	<ul><li>Table 7 "The</li></ul>	ermal characteristics": indica	ation per diode added				
	<ul> <li><u>Table 7</u>: R<sub>th(j</sub></li> </ul>	<sub>j-a)</sub> thermal resistance from	junction to ambient co	ndition amended			
	<ul> <li>Table 8 "Cha</li> </ul>	aracteristics": indication per	diode added				
	<ul> <li>Table 8 "Cha</li> </ul>	aracteristics": reference to T	able note 1 amended				
		1PS76SB21 C <sub>d</sub> minimum va	alue changed to typical	l value			
		d 2: amended					
		d 5: superseded by minimize	ed package outlines				
		acking information": added					
	Section 10 "	Soldering": added					
	Section 12 "I	Legal information": updated					
BAT721_SERIES_4	20040315	Product specification	-	BAT721_SERIES_3			
1PS76SB21_3	20040126	Product specification	-	1PS76SB21_2			

## 1PS76SB21; BAT721 series

Schottky barrier diodes in small packages

### 12. Legal information

#### 12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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### **NXP Semiconductors**

# 1PS76SB21; BAT721 series

Schottky barrier diodes in small packages

### 14. Contents

1	Product profile	1
1.1	General description	1
1.2	Features	1
1.3	Applications	1
1.4	Quick reference data	1
2	Pinning information	2
3	Ordering information	3
4	Marking	3
5	Limiting values	3
6	Thermal characteristics	4
7	Characteristics	4
8	Package outline	6
9	Packing information	6
10	Soldering	7
11	Revision history	9
12	Legal information 1	0
12.1	Data sheet status	10
12.2	Definitions	C
12.3	Disclaimers	0
12.4	Trademarks1	C
13	Contact information 1	0
14	Contents 1	11

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